

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or unavteries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out or i, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor and is officers, employees, uniotificated use, even if such claim any manner.



FGH20N60SFD 600 V, 20 A Field Stop IGBT

Features

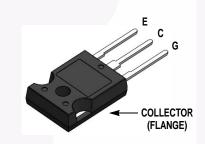
- High Current Capability
- Low Saturation Voltage: V_{CE(sat)} = 2.2 V @ I_C = 20A
- High Input Impedance
- Fast Switching
- RoHS Compliant

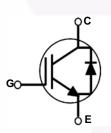
Applications

• Solar Inverter, UPS, Welder, PFC

General Description

Using novel field stop IGBT technology, Fairchild's field stop IGBTs offer the optimum performance for solar inverter, UPS, welder and PFC applications where low conduction and switching losses are essential.





Absolute Maximum Ratings

Symbol	Description		Ratings	Unit	
V _{CES}	Collector to Emitter Voltage		600	V	
V _{GES}	Gate to Emitter Voltage Transient Gate-to-Emitter Voltage		±20	V	
			±30	v	
L	Collector Current	@ T _C = 25°C	40	A	
I ^C	Collector Current	@ T _C = 100 ^o C	20	A	
I _{CM (1)}	Pulsed Collector Current	@ T _C = 25°C	60	А	
P _D	Maximum Power Dissipation	@ T _C = 25°C	165	W	
. D	Maximum Power Dissipation	@ T _C = 100 ^o C	66	W	
Т _Ј	Operating Junction Temperature		-55 to +150	°C	
T _{stg}	Storage Temperature Range		-55 to +150	°C	
Τ _L	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C	

Notes:

1: Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case	-	0.76	°C/W
$R_{\theta JC}$ (Diode)	C(Diode) Thermal Resistance, Junction to Case		2.51	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient	-	40	°C/W

March 2015

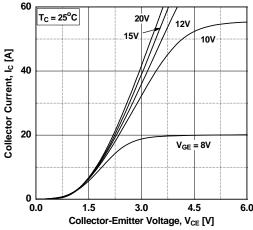
Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FGH20N60SFDTU	FGH20N60SFD	TO-247	Tube	N/A	N/A	30

Electrical Characteristics of the IGBT T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	teristics					
BV _{CES}	Collector to Emitter Breakdown Voltage	$V_{GE} = 0 V, I_{C} = 250 \mu A$	600	-	-	V
ΔBV_{CES} ΔT_J	Temperature Coefficient of Breakdown Voltage	V_{GE} = 0 V, I _C = 250 μ A	-	0.6	-	V/ºC
I _{CES}	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0 V$	-	-	250	μA
I _{GES}	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0 V$	-	-	±400	nA
On Charac	teristics					
V _{GE(th)}	G-E Threshold Voltage	I _C = 250 μA, V _{CE} = V _{GE}	4.0	5.0	6.5	V
		I _C = 20 A, V _{GE} = 15 V		2.2	2.8	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	$I_{C} = 20 \text{ A}, V_{GE} = 15 \text{ V},$ $T_{C} = 125^{\circ}\text{C}$	-	2.4	-	V
Dynamic C	Characteristics		I			
C _{ies}	Input Capacitance		-	940	-	pF
C _{oes}	Output Capacitance	V _{CE} = 30 V, V _{GE} = 0 V, f = 1 MHz	-	110	-	pF
C _{res}	Reverse Transfer Capacitance		-	40	-	pF
Switching	Characteristics					
t _{d(on)}	Turn-On Delay Time		-	13	-	ns
t _r	Rise Time		-	16	-	ns
t _{d(off)}	Turn-Off Delay Time	$V_{CC} = 400 \text{ V}, I_C = 20 \text{ A},$ $R_G = 10 \Omega, V_{GE} = 15 \text{ V},$ Inductive Load, $T_C = 25^{\circ}\text{C}$	-	90	-	ns
t _f	Fall Time		-	24	48	ns
Eon	Turn-On Switching Loss		-	0.37	-	mJ
E _{off}	Turn-Off Switching Loss		-	0.16	-	mJ
E _{ts}	Total Switching Loss		-	0.53	-	mJ
t _{d(on)}	Turn-On Delay Time		-	12	-	ns
t _r	Rise Time		-	16	-	ns
t _{d(off)}	Turn-Off Delay Time	$V_{\rm CC} = 400 \text{ V}, I_{\rm C} = 20 \text{ A},$	-	95	-	ns
t _f	Fall Time	$R_G = 10 \Omega$, $V_{GE} = 15 V$, Inductive Load, $T_C = 125^{\circ}C$	-	28	-	ns
			-	0.4	-	mJ
	Turn-On Switching Loss					mJ
E _{on}	Turn-On Switching Loss Turn-Off Switching Loss		-	0.28	-	IIIJ
E _{on}		-	-	0.28	-	mJ
E _{on} E _{off} E _{ts}	Turn-Off Switching Loss					
E _{on} E _{off}	Turn-Off Switching Loss Total Switching Loss	V _{CE} = 400 V, I _C = 20 A, V _{GE} = 15 V		0.69		mJ

Symbol	Parameter	Test Condition	Min.	Тур.	Max	Unit	
V_{FM}	Diode Forward Voltage	I _F = 10 A	$T_C = 25^{\circ}C$	-	1.9	2.5	V
			$T_{\rm C} = 125^{\rm o}{\rm C}$	-	1.7	-	
t _{rr} Diode F	Diode Reverse Recovery Time	$I_{\rm F} = 10$ A, $dI_{\rm F}/dt = 200$ A/µs	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	34	-	ns
			$T_{C} = 125^{\circ}C$	-	57	-	
Q _{rr}	Diode Reverse Recovery Charge		$T_C = 25^{\circ}C$	-	41	-	nC
			$T_{C} = 125^{\circ}C$	-	96	-	







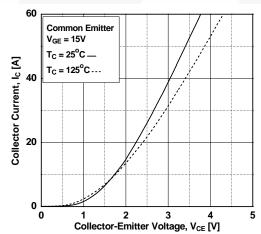


Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level

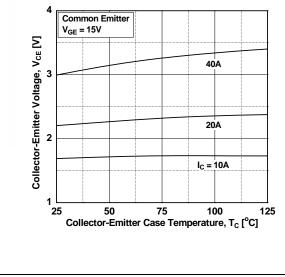


Figure 2. Typical Output Characteristics

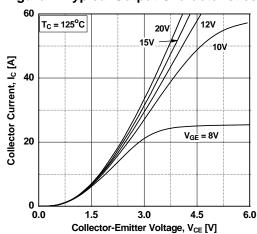


Figure 4. Transfer Characteristics

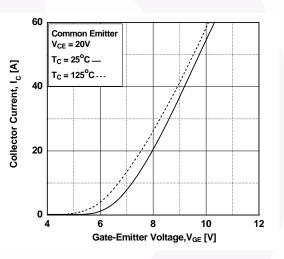
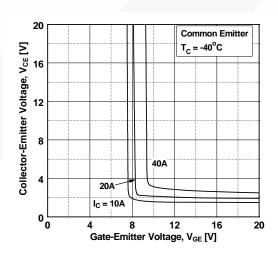
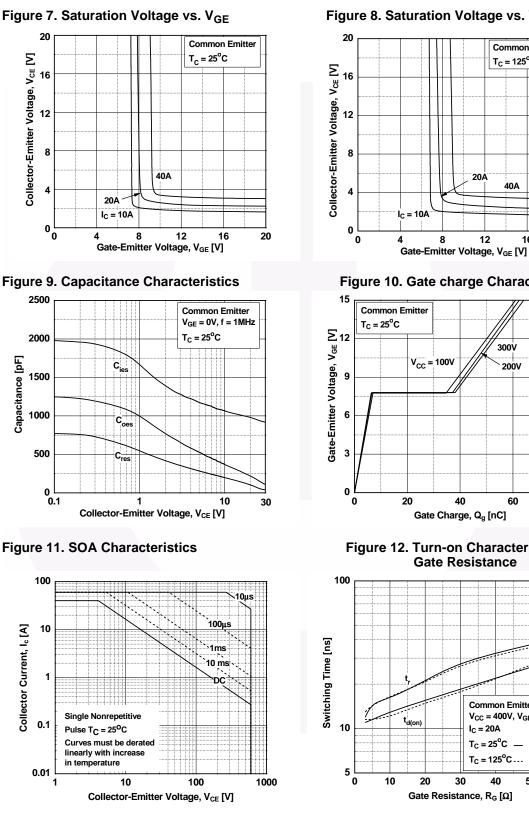


Figure 6. Saturation Voltage vs. V_{GE}





Typical Performance Characteristics

Figure 8. Saturation Voltage vs. V_{GE}

Common Emitter

T_C = 125°C

40A

16

20

Figure 10. Gate charge Characteristics

8

20A

12

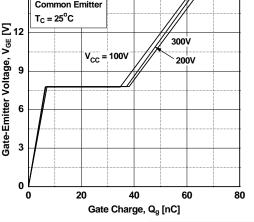
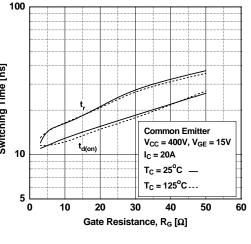
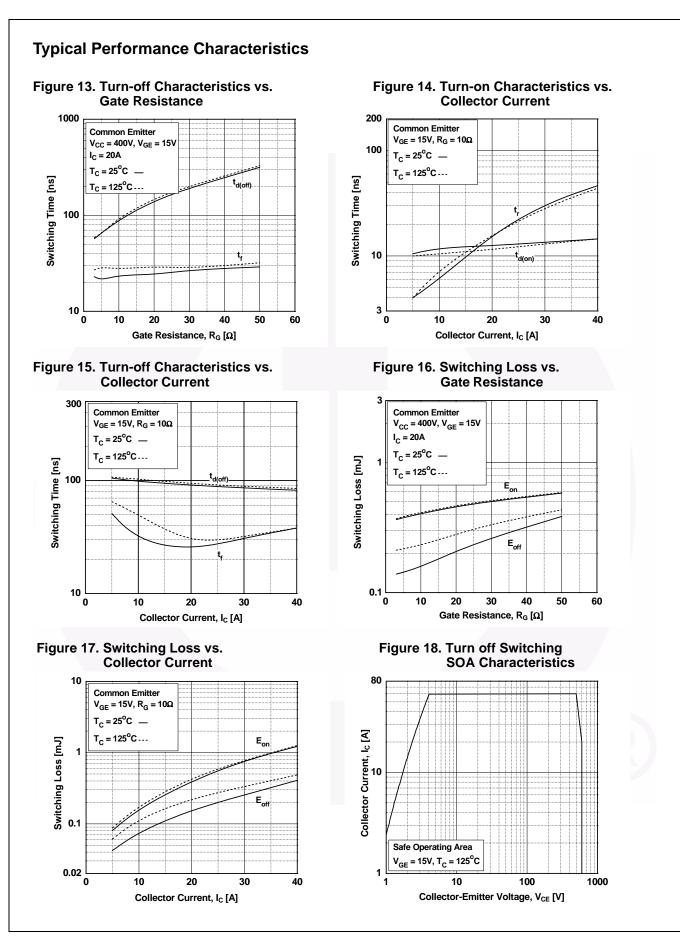


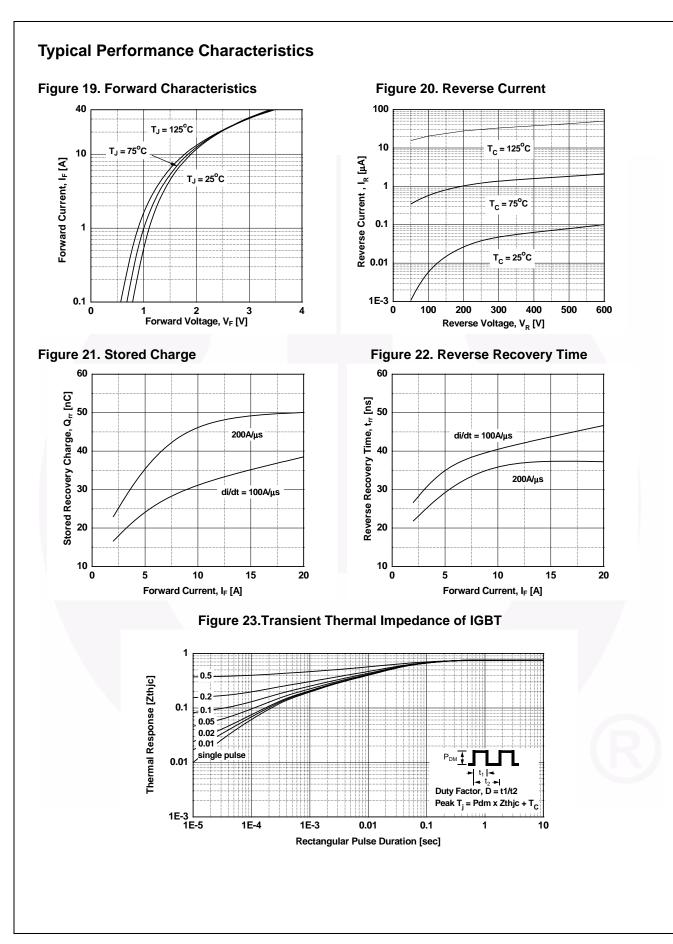
Figure 12. Turn-on Characteristics vs. **Gate Resistance**

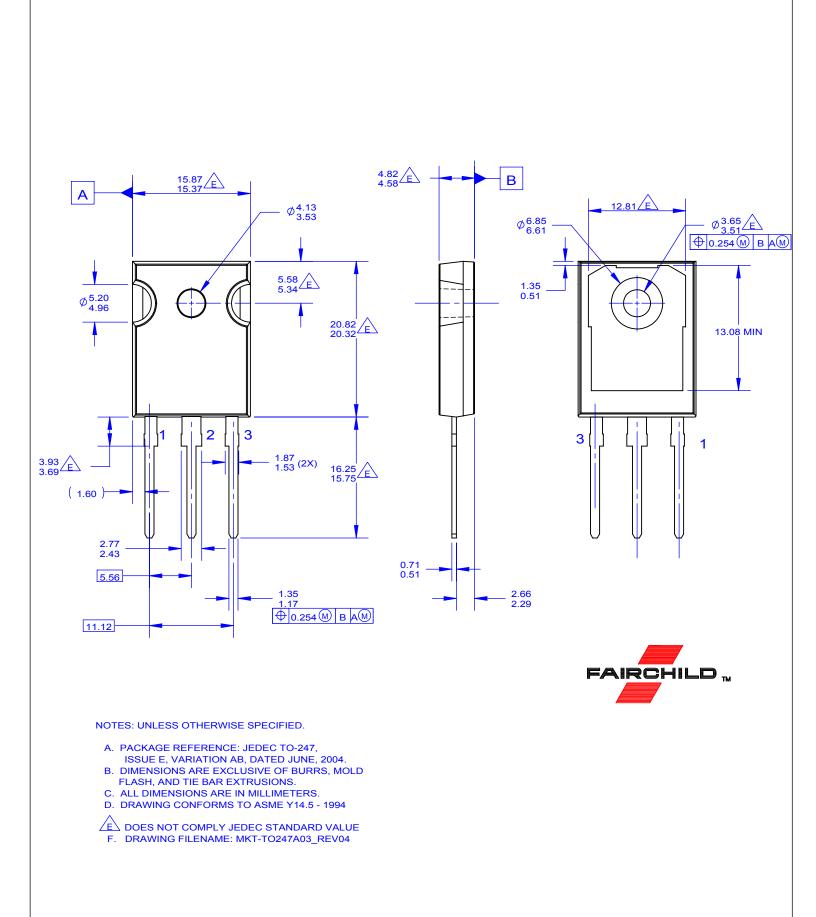


©2008 Fairchild Semiconductor Corporation FGH20N60SFD Rev. 1.5



©2008 Fairchild Semiconductor Corporation FGH20N60SFD Rev. 1.5





ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC